

T498D226K025ZTE600

Obsolete

B45196P, Tantalum, MnO₂ Tantalum, High Temperature, 22 uF, 10%, 25 VDC, SMD, Molded, High Temperature, N/A, 600 mOhms, 7343, Height Max = 3.1mm



| General Information | |
|---------------------|-------------------------------|
| Series | B45196P |
| Dielectric | MnO ₂ Tantalum |
| Style | SMD Chip |
| Description | SMD, Molded, High Temperature |
| Features | High Temperature, Automotive |
| RoHS | Yes |
| Termination | Tin |
| Qualifications | AEC-Q200 |
| AEC-Q200 | Yes |
| Notes | Obsolete. |

| Dimensions | |
|------------|----------------|
| Footprint | 7343 |
| L | 7.3mm +/-0.3mm |
| W | 4.3mm +/-0.3mm |
| H | 2.8mm +/-0.3mm |
| S | 1.3mm +/-0.3mm |
| F | 2.4mm +/-0.1mm |
| K | 1.8mm TYP |

| Specifications | |
|-----------------------|--|
| Capacitance | 22 uF |
| Capacitance Tolerance | 10% |
| Voltage DC | 25 VDC (85C), 19.92 VDC (125C), 16.75 VDC (150C) |
| Temperature Range | -55/+150°C |
| Rated Temperature | 85°C |
| Dissipation Factor | 4.5% |
| Failure Rate | N/A |
| Resistance | 0.6 Ohms (100kHz) |
| Ripple Current | 500 mAmps (25C), 450 mAmps (85C), 200 mAmps (125C) |
| Leakage Current | 5.5 uA |

| Packaging Specifications | |
|--------------------------|------------|
| Packaging | T&R, 178mm |
| Packaging Quantity | 750 |